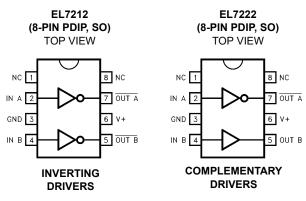
EL7202, EL7212, EL7222

High Speed, Dual Channel Power MOSFET Drivers

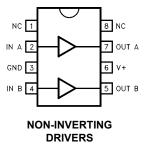
FN7282 Rev.2.01 Feb 18, 2020

The EL7202, EL7212, EL7222 ICs are matched dual-drivers that improve the operation of the industry standard DS0026 clock drivers. The Elantec versions are very high speed drivers capable of delivering peak currents of 2.0 amps into highly capacitive loads. The high speed performance is achieved by means of a proprietary "Turbo-Driver" circuit that speeds up input stages by tapping the wider voltage swing at the output. Improved speed and drive capability are enhanced by matched rise and fall delay times. These matched delays maintain the integrity of input-to-output pulse-widths to reduce timing errors and clock skew problems. This improved performance is accompanied by a 10 fold reduction in supply currents over bipolar drivers, yet without the delay time problems commonly associated with CMOS devices. Dynamic switching losses are minimized with non-overlapped drive techniques.

Pinouts



EL7202 (8-PIN PDIP, SO) TOP VIEW



Manufactured under U.S. Patent Nos. 5,334,883, #5,341,047

Features

- · Industry standard driver replacement
- · Improved response times
- Matched rise and fall times
- Reduced clock skew
- Low output impedance
- Low input capacitance
- High noise immunity
- Improved clocking rate
- · Low supply current
- · Wide operating voltage range
- · Pb-Free available (RoHS compliant)

Applications

- · Clock/line drivers
- CCD Drivers
- · Ultra-sound transducer drivers
- · Power MOSFET drivers
- · Switch mode power supplies
- · Class D switching amplifiers
- · Ultrasonic and RF generators
- Pulsed circuits

Ordering Information

Part Number	PART MARKING	TAPE & REEL	PACKAGE	PKG. DWG. #
EL7202CN (No longer available, recommended replacement: EL7202CSZ)	EL7202CN	-	8 Ld PDIP	E8.3
EL7202CSZ (See Note)	7202CSZ	-	8 Ld SOIC (Pb-free)	M8.15E
EL7202CSZ-T7 (See Note)	7202CSZ	7"	8 Ld SOIC (Pb-free)	M8.15E
EL7202CSZ-T13 (See Note)	7202CSZ	13"	8 Ld SOIC (Pb-free)	M8.15E
EL7212CNZ	EL7212CN Z	-	8 Ld PDIP* (Pb-free)	E8.3
EL7212CSZ (See Note)	7212CSZ	-	8 Ld SOIC (Pb-free)	M8.15E
EL7212CSZ-T7 (See Note)	7212CSZ	7"	8 Ld SOIC (Pb-free)	M8.15E
EL7212CSZ-T13 See Note)	7212CSZ	13"	8 Ld SOIC (Pb-free)	M8.15E
EL7222CSZ (See Note)	7222CSZ	-	8 Ld SOIC (Pb-free)	M8.15E
EL7222CSZ-T7 (See Note)	7222CSZ	7"	8 Ld SOIC (Pb-free)	M8.15E
EL7222CSZ-T13 (See Note)	7222CSZ	13"	8 Ld SOIC (Pb-free)	M8.15E

NOTE: Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

*Pb-free PDIPs can be used for through hole wave solder processing only. They are not intended for use in Reflow solder processing applications.

Absolute Maximum Ratings (T_A = 25°C)

Supply (V+ to Gnd) 16.	5V
Input Pins0.3V to +0.3V above	V+
Combined Peak Output Current.	4A
Storage Temperature Range65°C to +150)°C
Ambient Operating Temperature40°C to +85	ъ°С

Operating Junction Temperature
Power Dissipation
SOIC
PDIP

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

DC Electrical Specifications $T_A = 25^{\circ}C$, V = 15V unless otherwise specified

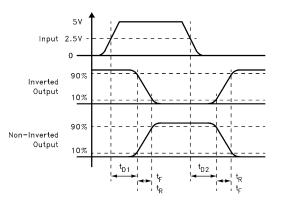
parameter	Description	Test Conditions	Min	Тур	Max	Units
INPUT						
VIH	Logic "1" Input Voltage		2.4			V
IIH	Logic "1" Input Current	@V+		0.1	10	μA
V _{IL}	Logic "0" Input Voltage				0.8	V
IIL	Logic "0" Input Current	@0V		0.1	10	μA
V _{HVS}	Input Hysteresis			0.3		V
OUTPUT		I	k	1		
R _{OH}	Pull-Up Resistance	I _{OUT} = -100mA		3	6	Ω
R _{OL}	Pull-Down Resistance	I _{OUT} = +100mA		4	6	Ω
I _{PK}	Peak Output Current	Source Sink		2 2		A
I _{DC}	Continuous Output Current	Source/Sink	100			mA
POWER SUPPLY					1	1
I _S	Power Supply Current	Inputs High/EL7202 Inputs High/EL7212 Inputs High/EL7222		4.5 1 2.5	7.5 2.5 5.0	mA
VS	Operating Voltage		4.5		15	V

AC Electrical Specifications

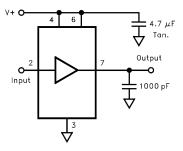
 $T_A = 25^{\circ}C$, V = 15V unless otherwise specified

parameter	Description	Test Conditions	Min	Тур	Max	Units			
SWITCHING CHARA	SWITCHING CHARACTERISTICS								
t _R	Rise Time	C _L = 500pF C _L = 1000pF		7.5 10	20	ns			
t _F	Fall Time	C _L = 500pF C _L = 1000pF		10 13	20	ns			
t _{D1}	Turn-On Delay Time	See Timing Table		18	25	ns			
t _{D2}	Turn-Off Delay Time	See Timing Table		20	25	ns			

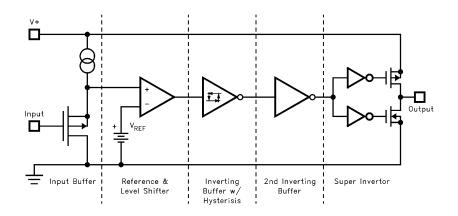
Timing Table



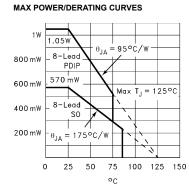
Standard Test Configuration



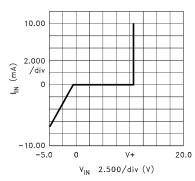
Simplified Schematic

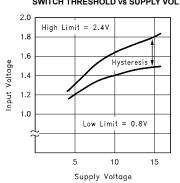


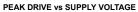
Typical Performance Curves

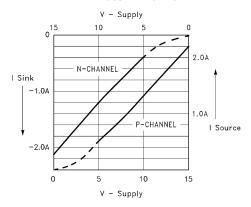




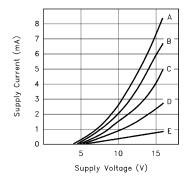






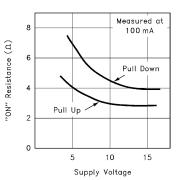


QUIESCENT SUPPLY CURRENT



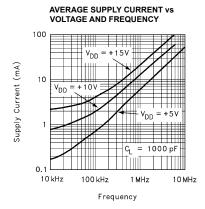
CASE:		
Device	Input Level	Curve
EL7202	GND	A
EL7202	GND, V+	B
EL7202	V+	C
EL7212	GND	C
EL7212	GND, V+	D
EL7212	V+	E
EL7222	GND	B
EL7222	GND, V+	C
EL7222	V+	D



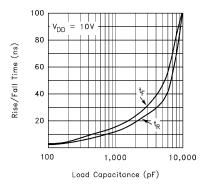


SWITCH THRESHOLD vs SUPPLY VOLTAGE

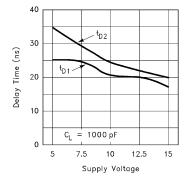
Typical Performance Curves (Continued)

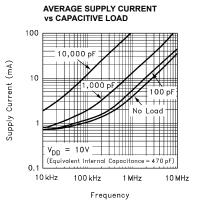


RISE/FALL TIME vs LOAD

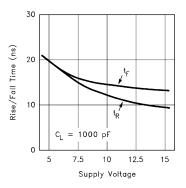


PROPAGATION DELAY vs SUPPLY VOLTAGE

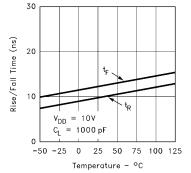




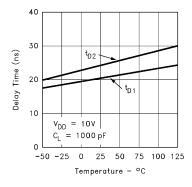
RISE/FALL TIME vs SUPPLY VOLTAGE



RISE/FALL TIME vs TEMPERATURE

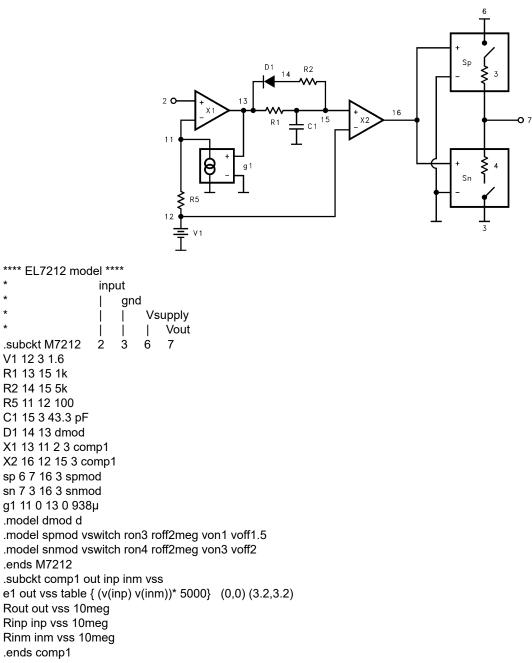


DELAY vs TEMPERATURE

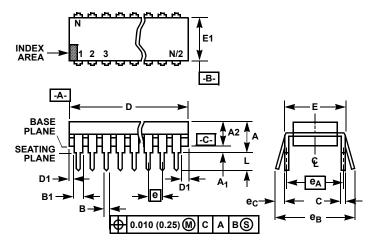


** *

EL7212 Macro Model



Package Outline Drawings



NOTES:

- 1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- 6. E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

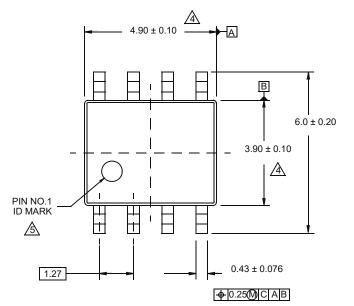
E8.3 (JEDEC MS-001-BA ISSUE D) 8 LEAD DUAL-IN-LINE PLASTIC PACKAGE (PDIP)

	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MIN MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
С	0.008	0.014	0.204	0.355	-
D	0.355	0.400	9.01	10.16	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100	BSC	2.54 BSC		-
e _A	0.300	BSC	7.62 BSC		6
e _B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
Ν	8		8		9

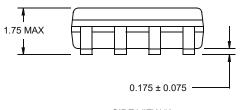
Rev. 0 12/93

M8.15E

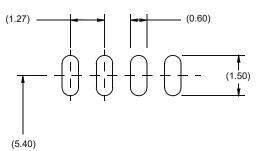
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE Rev 0, 08/09

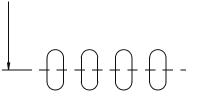


TOP VIEW

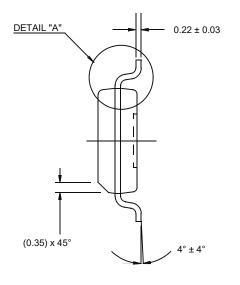


SIDE VIEW "A

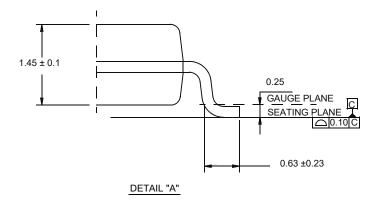




TYPICAL RECOMMENDED LAND PATTERN



SIDE VIEW "B"



NOTES:

- Dimensions are in millimeters.
 Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- 3. Unless otherwise specified, tolerance : Decimal ± 0.05
- Dimension does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25mm per side.
- 5. The pin #1 identifier may be either a mold or mark feature.
- 6. Reference to JEDEC MS-012.

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(Rev.4.0-1 November 2017)

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